

SANYO Semiconductors DATA SHEET

LA77000V — VHF Band RF Modulator (US3, 4ch Compatible)

Overview

The LA77000V is a VHF band RF module that supports US3, 4ch Compatible.

Functions

- RF VCO (AGC).
- RF Mixer.
- RF Buffer.
- Video clamp.
- White clipping.
- Audio FM.
- 4V regulator.
- Reference OSC.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply rating	V _{CC} max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 75°C	350*	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-55 to +150	°C

^{*} Mounted to the glass epoxy resin made board (114.3mm×76.1mm×1.6mm)

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	Vcc		5.0	V
Operating voltage range	V _{CC} op		4.5 to 5.5	V

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Electrical Characteristics/Operating Characteristics at Ta = 25 °C, $V_{CC} = 5.0V$, Measured with US3ch unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
Parameter			min	typ	max	Offic
Current drain 1	I _{CC} 1	No signal, pin 6 high	28	41	53	mA
Current drain 2	I _{CC} 2	No signal, pin 6 low	15	22	29	mA
Regulator voltage	Vreg	No signal	3.7	3.9	4.1	V
Antenna driver voltage	Vanton	Pin 6 high, 220Ω load	3.2	3.5	3.8	V
Negative Resistance (pin7)	-R	Cl≤100	1.2	2.2		kΩ
RF type						
Video carrier frequency accuracy	Fp	Fp (US3ch): 61.25MHz X'tal accuracy 30ppm	-25		25	kHz
Video carrier frequency stability	Fpt	X'tal accuracy 30ppm Ta = 4°C to 38°C	-25		25	kHz
Video carrier output US	Pus	No signal (Note 1)	85.5	87.5	89.5	dΒμ
Audio carrier output ratio	P/S	S: fp + 4.5MHz	14.5	16	17.5	dB
Audio 2 nd harmonic distortion	P/S2	S2: fp + 2 × 4.5MHz	50	65		dB
Audio 3 rd harmonic distortion	P/S3	S3: fp + 3 × 4.5MHz	45	55		dB
Chroma beat	P/CB	Vin = 3.58MHz, 0.6Vp-p CB: fp + 920kHz	65	74		dB
Video harmonic distortion	P/V2	Vin = 1MHz, 1Vp-p V2: fp + 2MHz	45	72		dB
Video type			1	I	I	
Video modulation	Мр	Vin = Stair step, 1Vp-p	75	80	85	%
White clip level	W _{CL}	Vin = Stair step, 1.5Vp-p	90	95	99	%
Differential gain	D _G	Vin = 10-Stair step, 1Vp-p (Note 2)	-5		5	%
Differential phase	D _P	Vin = 10-Stair step, 1Vp-p (Note 2)	-5		5	°C
Video signal frequency response	R _{fv}	Vin = CW, 1Vp-p 0.75 MHz to 3.75MHz	-1.1	-0.4	0.3	dB
Video S/N	V _{S/N}	Vin = 50% 4.2MHz LPF ON		50		dB
Audio type			•			
Audio carrier frequency accuracy	Fs	X'tal accuracy 30ppm	-5		5	kHz
Audio modulation	Ms	Ain = 1kHz, 1Vp-p (Note 3)	90	100	110	%
Maximum audio modulation	Msmx	THD < 3%	400			%
Audio distortion	THD	Ain = 1 kHz, 1Vp-p		0.4	2	%
Audio S/N	A _{S/N}	Ain = 1 kHz, 1Vp-p Vin = Color bar, 1Vp-p	45	50		dB

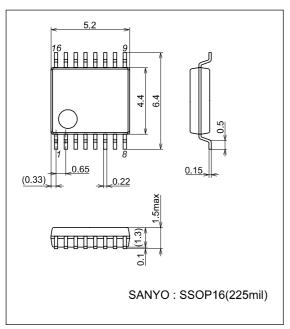
Note 1: 9.5dB added to the RFOUT value measured with a spectrum analyzer of the input impedance of 50Ω .

Note 2: Difference between 1 stair step and 8 stair step of 10 stair step.

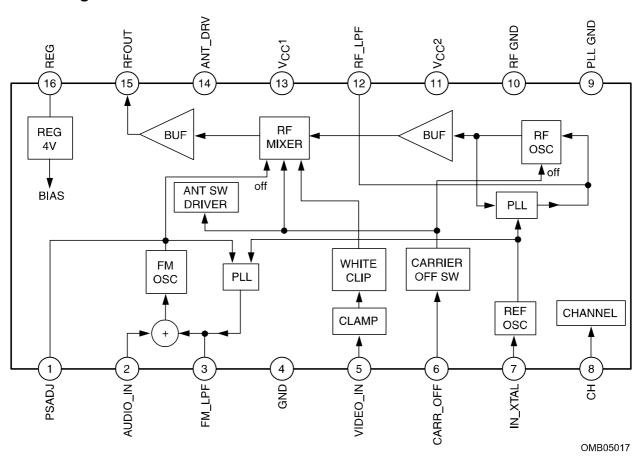
Note 3: $100\% = \pm 25$ kHz modulation.

Package Dimensions

unit : mm 3178B



Block Diagram



Pin equivalent circuit

1 111 60	Juivaic	nt circu	L	
Pin No.	Symbol	Voltage	Circuit	Remarks
1	P/S ADJ	2.7	10kΩ 500Ω 20PF 2kΩ 1	Capacitor and additionally a Resistor may inserted between the circuit and GND attenuate the audio inter-carrier level.
2	AUDIO IN	2.2	3kΩ 100kΩ 7/// ////	FM audio Input. Control pin of output FM oscilator for the PLL phase detector
		2.2	2.2V	charge pump.
4	GND	0		
5	VIDEO IN	2.6	100Ω 500Ω 5	Video Input Clamped with sink chip.
6	CARR OFF	-	100kΩ 25kΩ 6 20kΩ	Hi:14pin Hi RF Operating Lo:14pin Lo RF Stop

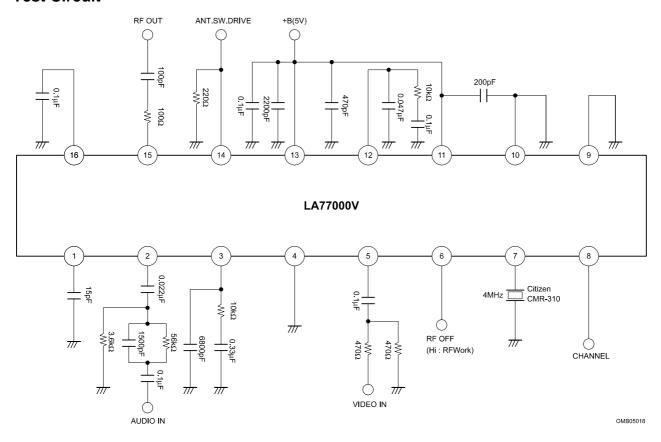
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Pin	from precedin Symbol	Voltage	Circuit	Remarks
No. 7	IN XTAL	3.5	5PF 100Ω 500Ω 7	4MHz oscillator inserted between the circuit and GND. External input of the 4MHz signal possible. Insertion of about 270kΩ resistor between the circuit and GND ensurescompatibility with 3.58MHz of VTR chroma sub-carrier. Insertion of about 270kΩ resistor between the circuit and VCC ensurescompatibility with 27MHz of D-STB reference.
8	CH	1.7	33kΩ 8 17kΩ 17kΩ	CH selector pin US3: 4.2V or more US4: 2.7V to 3.8V
9	PLL GND	0		PLL type GND
10	RF GND	0		RF type GND
11	V _{CC} 2	5.0		RF VCO type V _{CC}
12	RF LPF	2.6	2.8V 1κΩ 2.2V 1/1/1/1/1/1/1/1/1/1/1/1/1/1/1/1/1/1/1/	Control pin of output RF oscillator for the PLL phase detector charge pump.

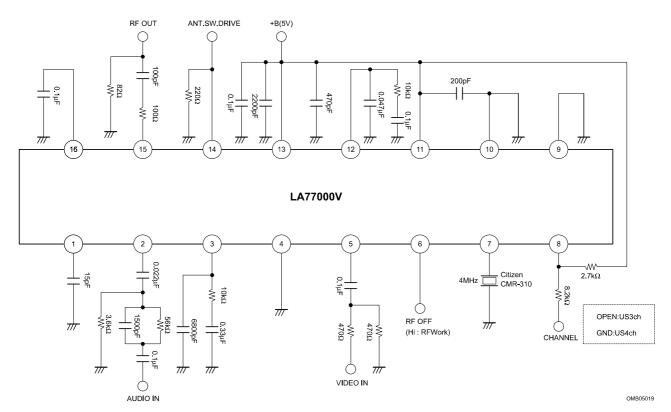
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Pin	Symbol	Voltage	Circuit	Remarks			
No.			Shoult				
13	V _{CC} 1	5.0		Vcc			
14	ANT	3.5		Antenna SW driver pin.			
	DRV		50kΩ 1kΩ 140kΩ 100kΩ	15mA drive.			
15	RF OUT	3.0	1.5Ω	RF mixed signal output.			
16	REG	3.9	16 56.5kΩ 25kΩ	Regulator output.			

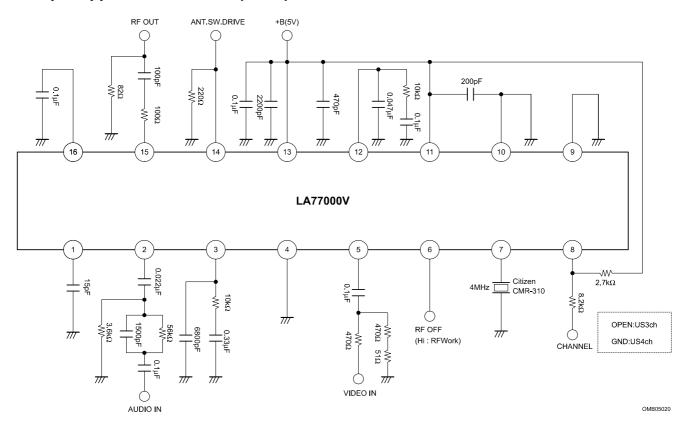
Test Circuit



Sample Application Circuit 1 (USch) for VCR



Sample Application Circuit 2 (USch) for STB



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